Overvoltage Protector IC with Reverse Current Protection

NO.EA-313-151124

OUTLINE

The R5528Z001A is a CMOS-based overvoltage protector IC with reverse current protection that use an NMOS pass transistor to achieve ultra-low on resistance (Typ. 54mΩ). Overvoltage protection threshold is as high as 6.8V±3%. Also, continuous current capability is as high as 3A.

Internally, the R5528Z001A consists of a reverse current protection circuit, a soft-start circuit, a startup debounce circuit, an undervoltage lockout (UVLO) circuit, and a thermal shutdown circuit.

The R5528Z001A is offered in a small and thin WLCSP-9-P1 package which achieves the smallest possible footprint solution on boards where area is limited.

FEATURES

- Input Voltage Range (V_{IN}) ································ 2.3V to 36V
- Output Current (I_{OUT})·· Max. DC 3A
- Switch On Resistance (R_{ON}) ····························· 54mΩ (V_{IN} = 5.0V, I_{OUT} = 100mA)
- OVP Threshold Accuracy ································· 6.8V±3%
- PG Function
- Reverse Current Protection Circuit
- Soft-start Circuit
- Startup Debounce Circuit ································· 15ms
- Thermal Shutdown Circuit
- Package·· WLCSP-9-P1

APPLICATIONS

- Smartphones, Tablet PCs
- Portable devices

BLOCK DIAGRAMS

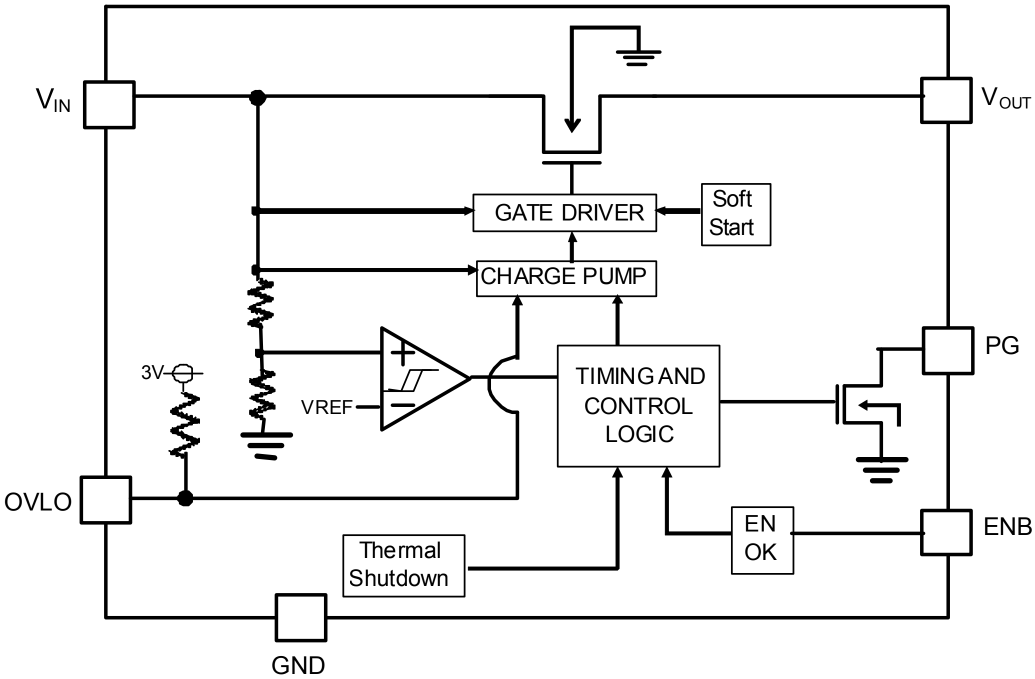


Figure 1. R5528Z001A

SELECTION GUIDE

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R5528Z001A-E2-F	WLCSP-9-P1	5,000pcs	Yes	Yes

PIN CONFIGULATIONS

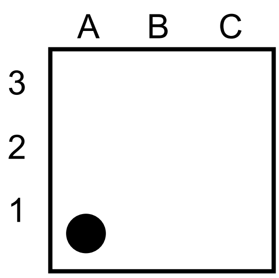


Figure 2. Top View

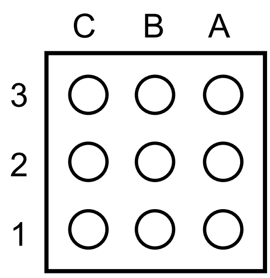


Figure 3. Bottom View

PIN DESCRIPTION

Pin No.	Symbol	Pin Description
A1	PG	Open Drain Flag Output Pin PG is driven low after input voltage is stable between minimum V_{IN} and $V_{IN-OVLO}$ after debounce (delay).
A2	OVLO	Overvoltage Lockout Input Pin Applying a voltage less than OVLO threshold (V_{OVLO_TH}) to the overvoltage lockout input pin can turn off a switch. When the overvoltage lockout input pin is Open, it outputs an OVLO open voltage (V_{OVLO_OP}).
A3	ENB	Active-Low ENB Input Pin
B1, C1	V_{IN}	Input Pin
B2	I.C	Internally Connected to Ground Unconnected or connected to GND
B3, C3	V_{OUT}	Output Pin
C2	GND	Ground Pin

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
V_{IN}	Input Voltage	-0.3 to 40	V
V_{OUT}	Output Voltage	-0.3 to 8.0	V
V_{ENB}	ENB Pin Input Voltage	-0.3 to 6.5	V
V_{PG}	PG Pin Voltage	-0.3 to 6.5	V
V_{OVLO}	OVLO Pin Input Voltage	-0.3 to 6.5	V
I_{PG}	PG Pin Current	14	mA
I_{OUT}	Output Current	3.0	A
P_D	Power Dissipation (High Wattage Land Pattern)[*1]	1190	mW
Topt	Operating Temperature Range	-40 to +85	°C
Tstg	Storage Temerature	-55 to +125	°C

[*1] Refer to *POWER DISSIPATION* for detailed information about Power Dissipation and High Wattage Land Pattern.

ABSOLUTE MAXIMUM RATINGS
Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)
All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

POWER DISSIPATION (WLCSP-9-P1)

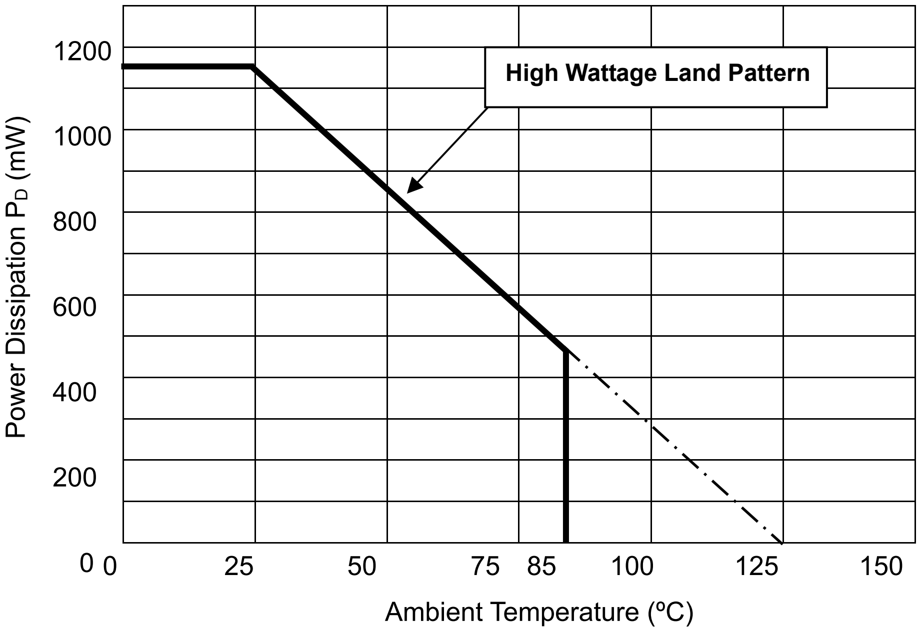
Power Dissipation (P_D) of the package is dependent on PCB material, layout, and environmental conditions. The following conditions are used in this measurement.

Measurement Conditions

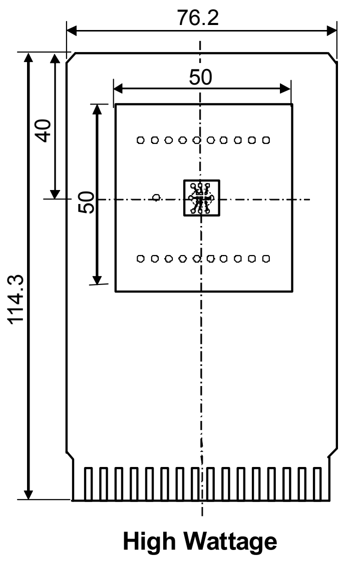
	High Wattage Land Pattern
Environment	Mounting on Board (Wind Velocity 0m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-layers)
Board Dimensions	76.2mm x 114.3mm x 1.6mm
Copper Ratio	Top, Back side: Approx. 60%, 2nd, 3rd: 100%
Through - hole	ϕ 0.5mm x 29pcs

Measurement Result (Ta=25°C, Tjmax=125°C)

	High Wattage Land Pattern
Power Dissipation	1190mW
Thermal Resistance	θja＝(125-25°C)/1.19W＝84°C/W



Power Dissipation



High Wattage

Measurement Board Pattern

IC Mount Area (Unit: mm)

ELECTRICAL CHARACTERISTICS

V_{IN} = 2.3V to 36V, I_{OUT} = 1mA, C_{IN} = 1μF, C_{OUT} =1μF, unless otherwise noted. Typical values are V_{IN} = 5V and Ta = 25°C.
The specifications surrounded by [ ] are guaranteed by Design Engineering at - 40ºC ≤ Ta ≤ 85ºC.

(Ta=25°C)

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V_{IN}	Input Voltage		2.3		36	V
I_{IN}	Input Supply Current	V_{ENB} = 0V, V_{IN} = 5V, I_{OUT} = 0mA		50	120	μA
I_{IN_DIS}	Input Disable Current	V_{ENB} = 0V, V_{IN} = 5V, V_{OVLO} = 0V		40	120	μA
I_{IN_Q}	Input Shutdown Current	V_{ENB} = 5V, V_{IN} = 5V, V_{OUT} = 0V		1.0	12	μA
$I_{OUT\text{-}DIS}$	Output Disable Current	V_{ENB} = 0V, V_{OUT} = 5V, V_{IN} = 5V, V_{OVLO} < $V_{OVLO\text{-}TH}$			3	μA
		V_{ENB} = 0V, V_{OUT} = 5V, V_{IN} > $V_{IN\text{-}OVLO}$				
$I_{OUT\text{-}SD}$	Output Shutdown Current	V_{ENB} = 5V, V_{OUT} = 5V, V_{IN} = 5V			5.5	μA
R_{ON}	On Resistance	V_{IN} = 5V, I_{OUT} = 100mA		54	100	mΩ
$V_{IN\text{-}OVLO}$	Overvoltage Protection Threshold	IN rising	6.6	6.8	7.0	V
		IN falling	6.4			V
C_{OUT}	OUT Load Capacitance				1000	μF
V_{OVLO_OP}	OVLO Open voltage	V_{ENB} = 0V, V_{IN} = 5.0V		3.0	3.6	V
R_{OVLO_PU}	OVLO Pull-up Resistance			500		kΩ
V_{OVLO_TH}	OVLO Force Off Voltage		0.6	1.0	1.4	V
V_{IH}	ENB Input High Voltage		1.4			V
V_{IL}	ENB Input Low Voltage				0.4	V
I_{ENB}	ENB Input Leakage		-1		1	μA
V_{OL}	PG Output Low Voltage	I_{SINK} = 1mA			0.4	V
V_{PG_LEAK}	PG Leakage Current	V_{IO} = 3.3V*2	-1		1	μA
t_{DEB}	IN Debounce Time	starts when 2.3V < V_{IN}(5V) < $V_{IN\text{-}OVLO}$ and ends when charge-pump is turned on*3	10	15	35	ms
t_{SS}	Soft-start Time	starts when 2.3V < V_{IN} < $V_{IN\text{-}OVLO}$ and ends when V_{OUT} = 90% of V_{IN}		30		ms
t_{ON}	Turn-on Time During Soft-start	V_{IN} = 5V, R_L = 50Ω, C_L = 10uF, starts when V_{OUT} = 20% of V_{IN} and ends when V_{OUT} = 80% of V_{IN}*3	1.5	-		ms
t_{OFF}	Turn-off Time	R_L = 50Ω, starts when V_{IN} > V_{OVLO} (2V/μs) and ends when V_{OUT} = 80% of V_{IN}		1.5		μs
		starts when V_{ENB} is switched from "L" to "H", ends when V_{OUT} = 80% of V_{IN}, R_L = 50Ω		84		μs
T_{SHDN}	Thermal Shut Down			150		°C
T_{HYST}	Thermal Hysteresis			20		°C
V_{UVREL}	UVLO Release Voltage	V_{IN} rising		2.05	2.3	V
V_{UVHYS}	UVLO Hysteresis	V_{IN} falling		0.15		V

All test items listed under *ELECTRICAL CHARACTERISTICS* are done under the pulse load condition (Tj≈Ta=25ºC) except Soft-Start Time and Turn-off Time and UVLO Hysteresis.

*2 Refer to *TYPICAL APPLICATION AND TECHNICAL NOTES.*

*3 Refer to *TIMING CHART*.

TIMING CHART

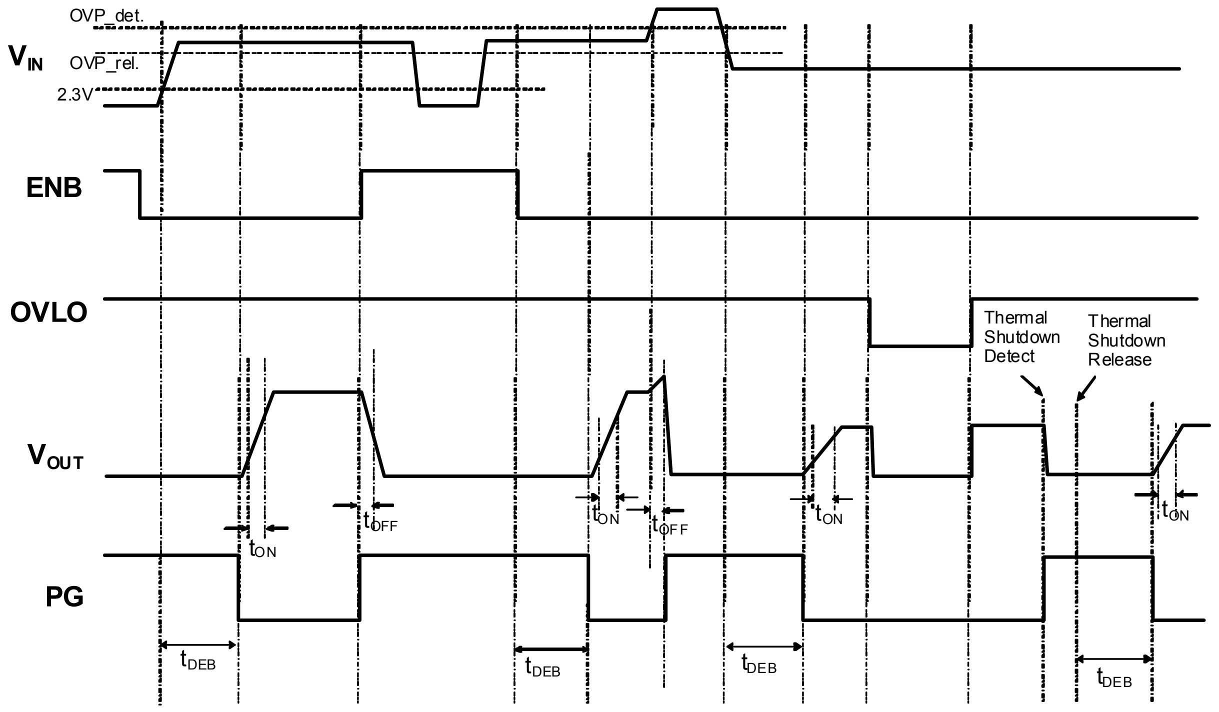


Figure 4. Timing Chart

TYPICAL APPLICATIONS AND TECHNICAL NOTES

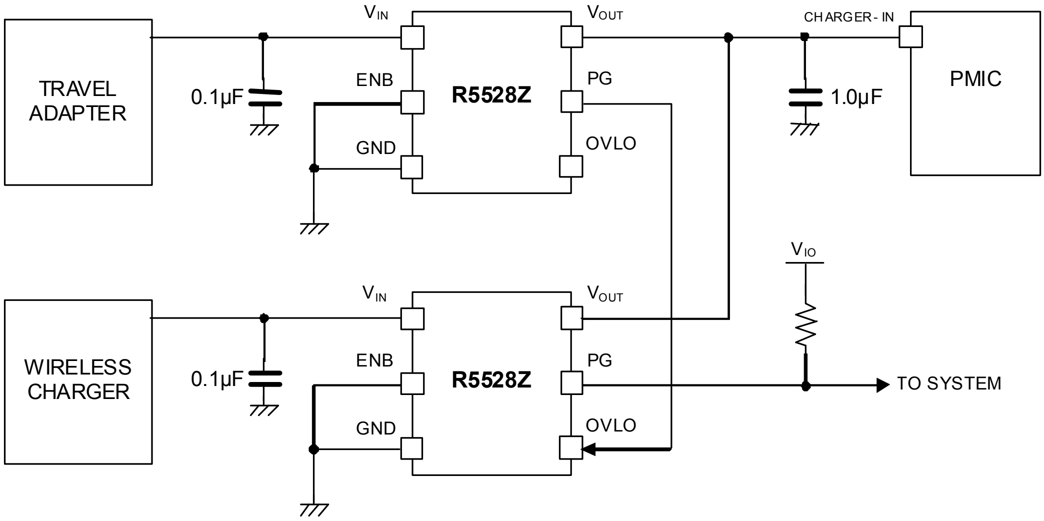


Figure 5. Typical Applications

Technical Notes

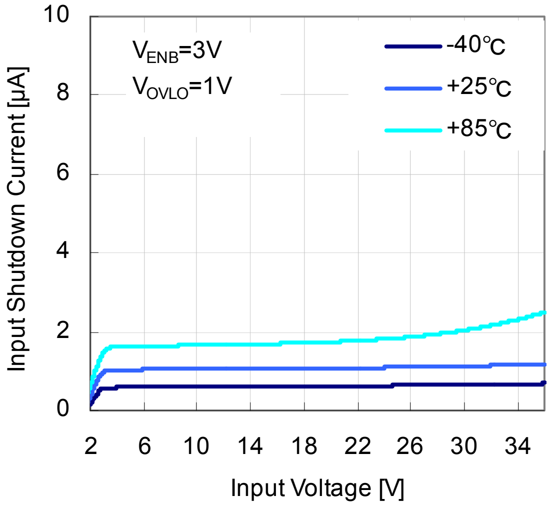
The R5528Z001A does not require any bypass capacitor between V_{IN} and GND. However, connecting a 0.1μF or more capacitor between V_{IN} and GND may improve the performance against the noise.

If there's any possibility of generating spike noise due to the parasitic element (inductance) of V_{IN}, connect an appropriate-sized capacitor between V_{IN} and GND.

TYPICAL CHARACTERISTIC

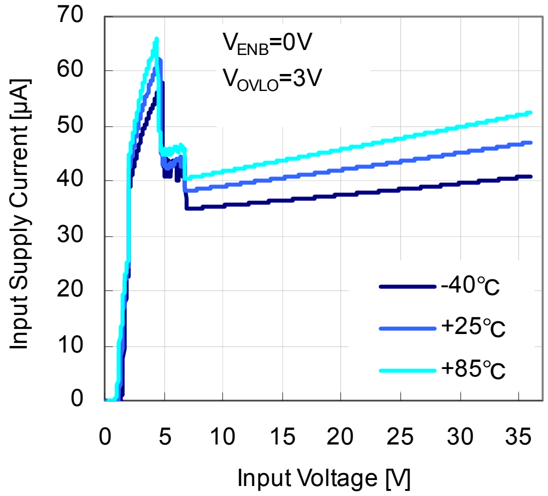
1) Input Shutdown Current VS. Input Voltage

R5528Z001A



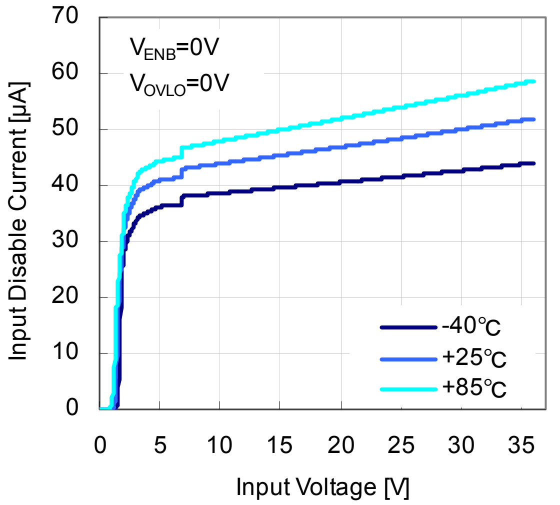
2) Input Supply Current VS. Input Voltage

R5528Z001A



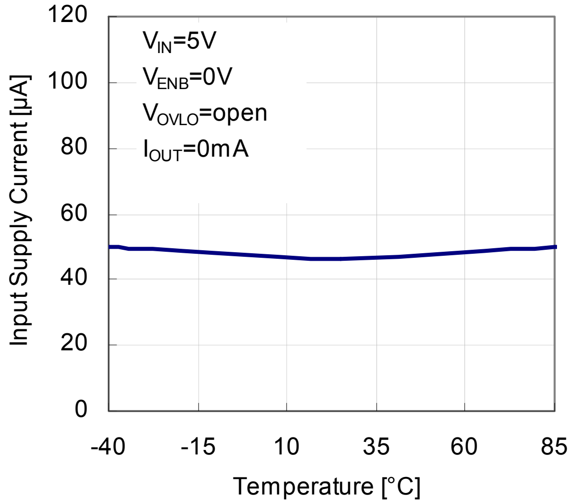
3) Input Disable Current VS. Input Voltage

R5528Z001A



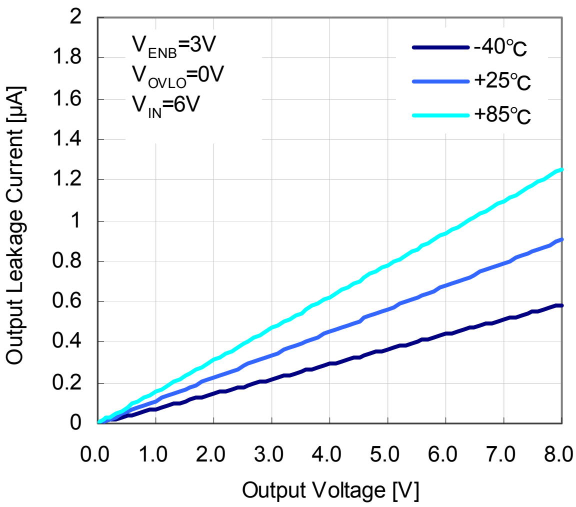
4) Input Supply Current VS. Temperature

R5528Z001A



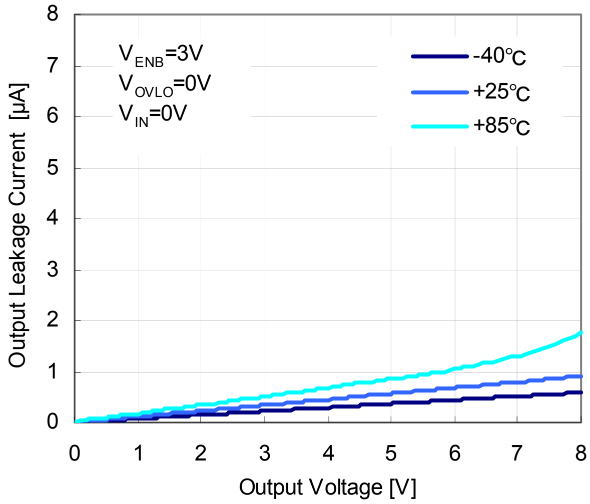
5) Output Leakage Current (6V) VS. Output Voltage

R5528Z001A



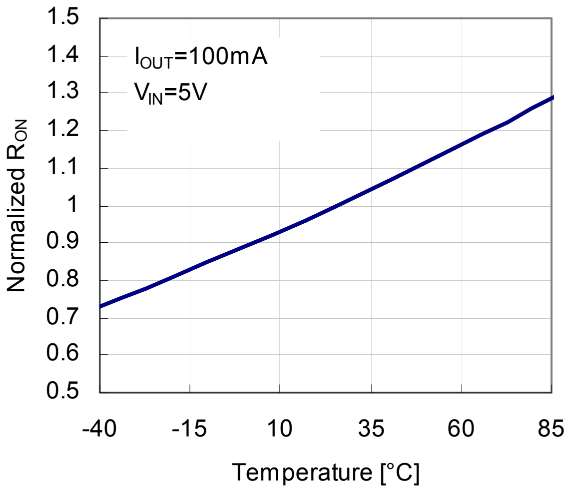
6) Output Leakage Current (0V) VS. Output Voltage

R5528Z001A



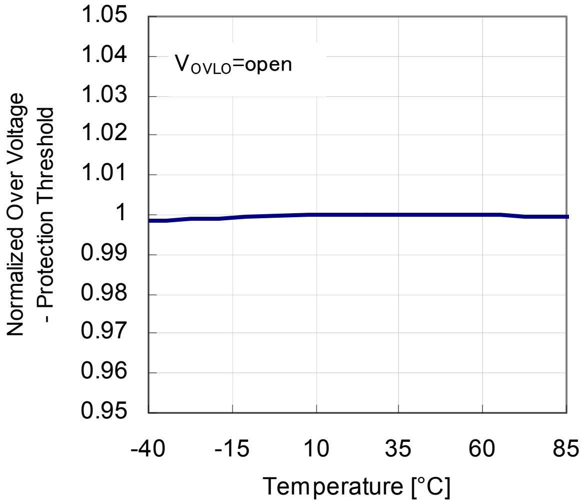
7) Normalized On-Resistance VS. Temperature

R5528Z001A



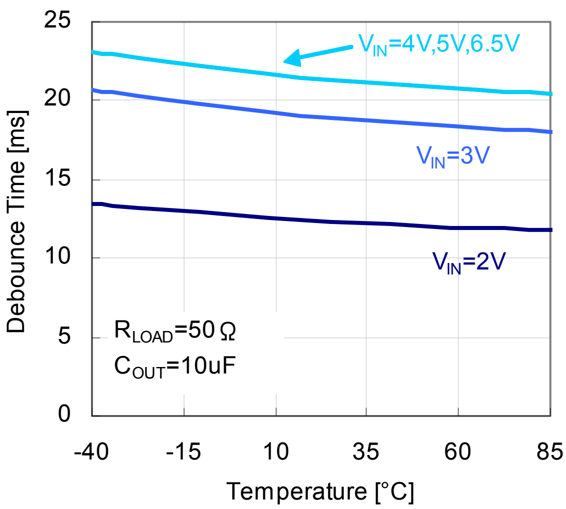
8) Normalized Overvoltage Protection Threshold (IN rising) VS. Temperature

R5528Z001A



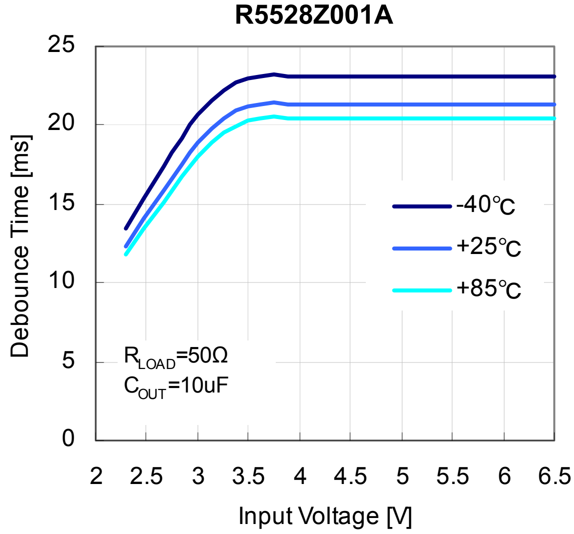
9) Debounce Time VS. Temperature

R5528Z001A

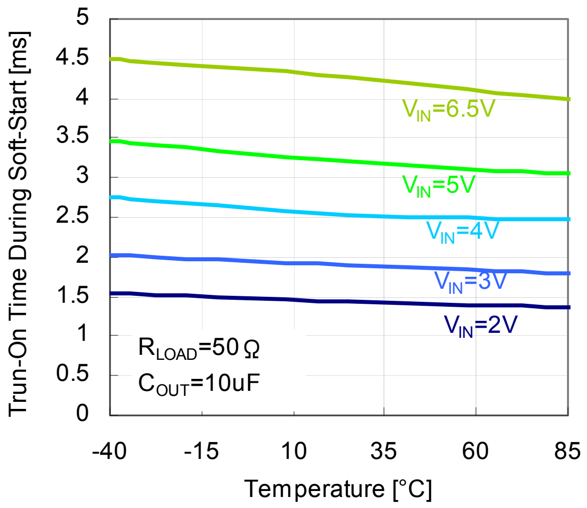


10) Debounce Time VS. Input Voltage

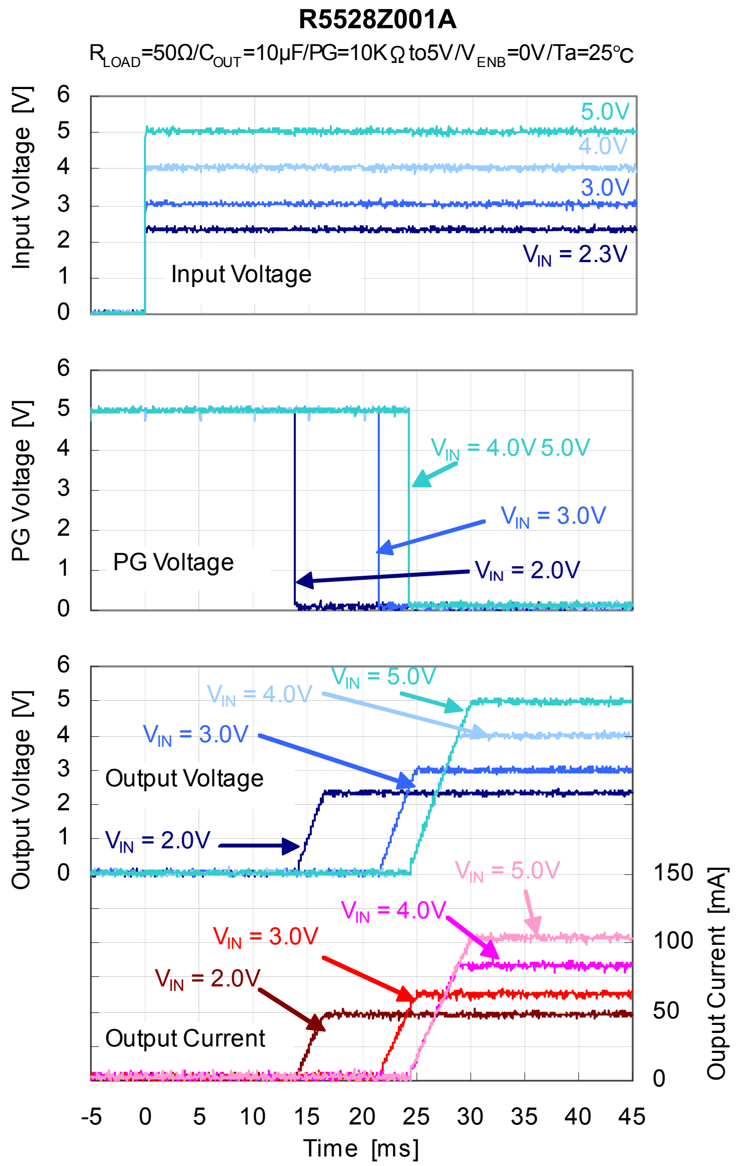
R5528Z001A



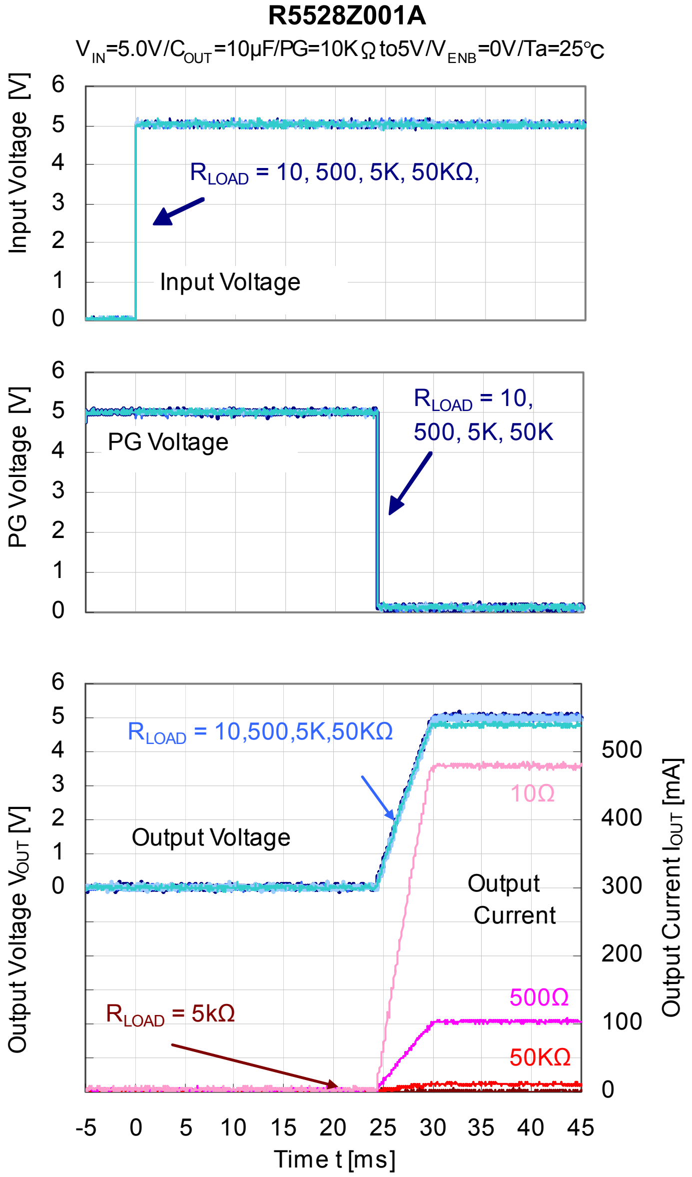
11) Trun-On Time VS. Temperature



12) Power-Up Responce (V_{IN} = 2.3V/ 3.0V/ 4.0V/ 5.0V)



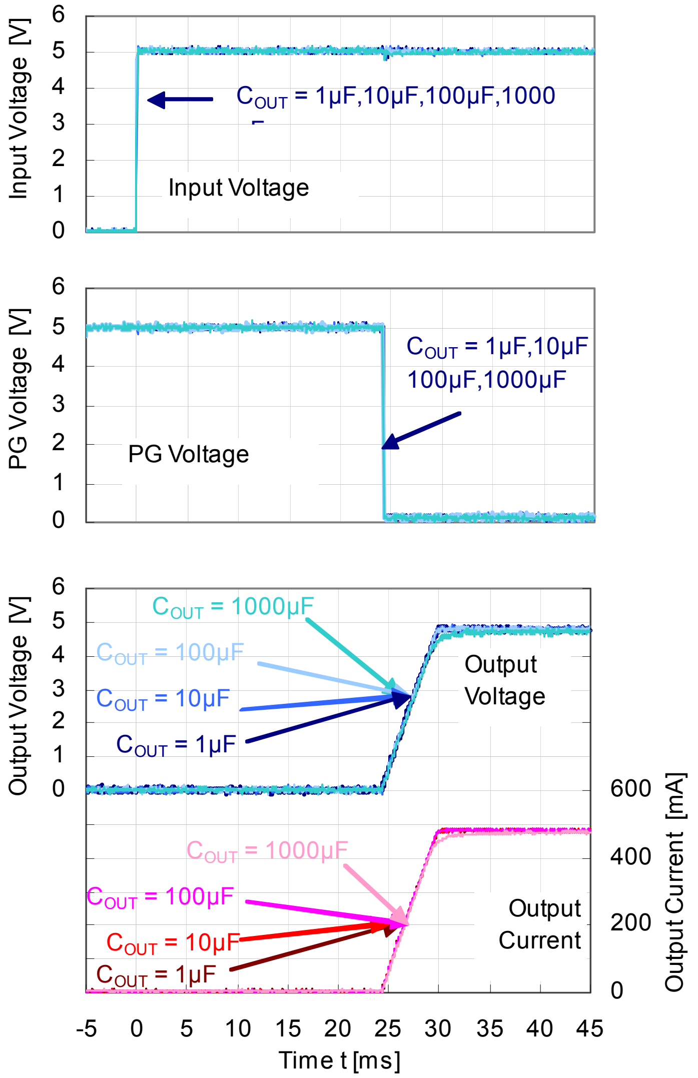
13) Power-Up Responce (R_{OUT} = 10Ω/ 50Ω/ 5KΩ/ 50KΩ)



14) Power-Up Responce (C_{OUT} = 1µF/ 10µF/ 100µF/ 1000µF)

R5528Z001A

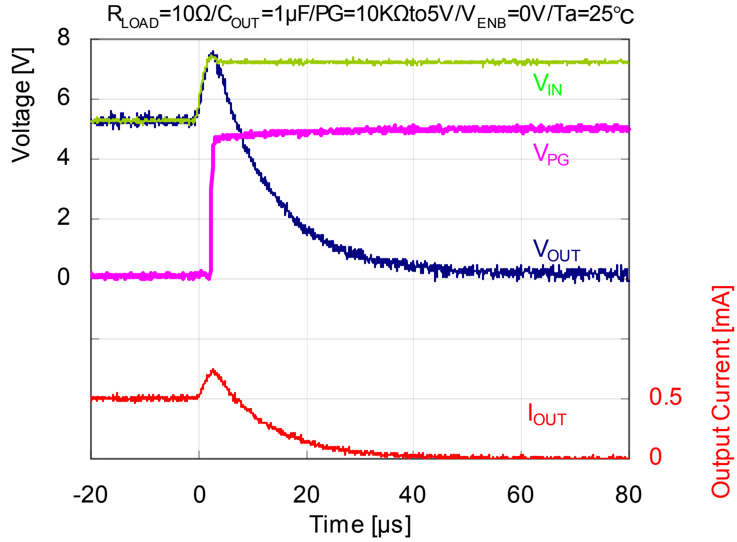
V_{IN}=5V/R_{LOAD}=10Ω/PG=10KΩ to5V/V_{ENB}=0V/Ta=25°C



15) Overvoltage Fault Response

R5528Z001A

R_{LOAD}=10Ω/C_{OUT}=1µF/PG=10KΩto5V/V_{ENB}=0V/Ta=25°C



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